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Effect of Amino Acid Additives on Crystal Growth Parameters and Properties of Ammonium Dihydrogen Phosphate Crystals

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1. Introduction

The isomorphous ammonium dihydrogen phosphate (ADP) and potassium dihydrogen phosphate (KDP) are technologically important crystals grown in large size for various applications. ADP crystal is of more appeal due to its piezo-electric property (Tukubo et al., 1989). Studies on ADP crystals attract interest because of their unique nonlinear optical, dielectric and antiferroelectric properties (Gunning et al., 2001). ADP crystals are widely used as the second, third and fourth harmonic generators for Nd: YAG, Nd: YLF lasers and for electro-optical applications such as Q-switches for Ti: Sapphire, Alexandrite lasers, as well as for acousto-optical applications. ADP crystal has found applications in NLO, electro-optics, transducer devices and as monochromators for X-ray fluorescence analysis.

The room temperature structure of ADP determined by X-ray diffraction analysis was reported by Ueda (1948). Tenzer et al (1958) and Hewat (1973) examined the structure by neutron diffraction analysis. The projection of the structure onto the b, c plane is shown in Figure 1.

ADP differs from KDP by having extra N-H-O hydrogen bonds which connect PO₄ tetrahedra with neighbouring NH₄ group. Each oxygen atom is connected with another oxygen atom in the neighboring PO₄ ion and with a nitrogen atom in a neighbouring NH₄ ion by two Kinds of bonds: (O-H-O) and (N-H-O). According to the positional refinements of each atom in ADP by X-ray diffraction study (Srinivasan, 1997), both above and below the phase transition point, each NH₄ ion at the potassium position in KDP structure is shifted to the off-center position by forming two shorter and two longer bonds with four PO₄ tetrahedra at low temperature phase. When an oxygen is connected with the shorter N-H-O bond, it tends to keep the other proton off in the O-H-O bond and when with the longer N-H-O bond it tends to take the acid proton nearby. Thus the extra hydrogen bonds produce a distorted NH₄ ion lattice at low temperature and co-operate with the acid protons in causing proton configurations different from those found at low temperature in KDP (Matsushita et al., 1987). As a representative hydrogen bonded material, ADP has attracted extensive attention in the investigation of hydrogen bonding behaviors in crystal and the relationship between crystal structures and their properties.

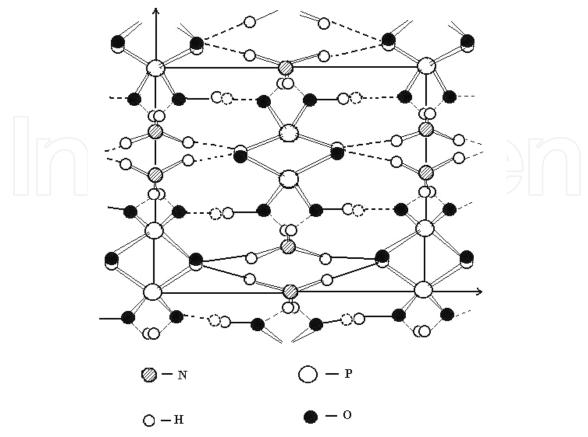


Fig. 1. The (100) projection of ADP structure.

Several researchers have carried out a lot of studies in pure and doped ADP crystals (Zaitseva et al., 2001; Ren et al 2008). In ADP and KDP crystal growth, the metallic cations present in the solutions, especially materials with high valency were considered to strongly affect the growth habit and optical properties of the crystals. The most dangerous impurities which affect the growth habit are trivalent metals Cr³⁺, Fe³⁺ and Al³⁺ (Alexandru et al., 2003). Even after repeated recrystallization, the presence of small amount of those kinds of impurities in the solution suppresses the crystal quality and growth rate. Here comes the importance of beneficial effects of additives in the crystal growth. An additive can suppress, enhance or stop the growth of crystal completely and its effects depend on the additive concentration, supersaturation, temperature and pH of the solution. Some dopants are added to suppress the effect of metal ion impurities on ADP and KDP crystals. For example, EDTA and KCl reduces the effect of metal ion impurities and enhance the metastable zone width and increases the growth rate of the crystals (Rajesh et al., 2000; Podder 2002; Meenakshisundaram et al., 2009). The addition of such kind of dopants does not remove the impurities present in the solution; it just reacts with the metal ions and is making complexes. By making complex, the ions become bigger in size and it is not possible to enter into the growing crystal (Li et al., 2005; Asakuma et al., 2007). Studies have also been made about the effect of additives on growth, habit modification and structure of ADP (Davey et al., 1974; Boukhris et al., 1998). The adsorption of impurities at different sites can cause growth inhibitions, even block the growing surface and in consequence stop the growth process. However, the adsorbed impurities may simultaneously lead to a reduction in the edge free energy, which results in an increase in crystal growth rate (Rak et al., 2005). Several dopants

help in the growth of ADP crystals at with higher growth rate and enhancement in the various properties of the crystals. The growth promoting effect is observed in the presence of organic additives (Kern et al., 1992; Bhagavannarayana et al., 2006) as well as inorganic additives (Shantha et al., 1997; Podder et al, 2001).

Amino acid family crystals exhibit excellent nonlinear optical and electro-optical properties. Reports are available in literature on the doping of amino acids in technologically important crystals and the enhancement of the material properties like nonlinear optical and ferroelectric properties. For example, enhancement of Second Harmonic Generation (SHG) efficiency has been reported in L-arginine doped KDP crystals (Parikh et al., 2007). Kumaresan et al (2008) reported the doping of amino acids (L-glutamic acid, L-histidine, L-valine) with KDP and studied its properties. The effects on various properties of L-theronine, DL-theronine and L-methionine admixtured Triglycine Sulfate (TGS) crystals were studied and the authors reported that the admixtured TGS crystal has different properties compared to pure TGS crystal (Meera et al., 2004). Batra et al (2005) investigated the growth kinetics of KDP and TGS crystals doped with L-arginine phosphate monohydrate. The addition of L-arginine decreases the value of dielectric constant of KDP crystals (Meena et al., 2008).

In the light of research work being done on ADP crystals, to improve their growth and other characteristics, it was thought interesting and worthwhile to investigate the effects of amino acid materials L-arginine monohydrochloride ($C_6H_{15}N_4O_2Cl$) and L-alanine ($C_3H_7NO_2$) on nucleation studies, growth and properties of ADP crystals for both academic and industrial uses. The reason for choosing the dopants is that L-arginine monohydrochloride and L-alanine are efficient NLO materials under the amino acid category. Monaco et al (1987) discovered NLO material L-arginine monohydrochloride, which belongs to space group P2₁ of monoclinic system with two molecules in the asymmetric unit. L-alanine crystallizes in orthorhombic system with noncentrosymmetric space group P2₁2₁2₁ (Razzetti et al., 2002).

2. Experimental studies

2.1 Determination of solubility and metastable zone width

Metastable zone width is an essential parameter for the growth of large size crystals from a solution, since it is the direct measure of the stability of the solution in its supersaturated region. Metastable zone width is an experimentally measurable quantity which depends on number of factors, such as stirring rate, cooling rate of the solution and presence of additional impurities (Nyvlt et al., 1970; Sangwal 1989; Zaitseva et al., 1995). Ammonium dihydrogen phosphate, L-arginine monohydrochloride (LAHCI) and L-alanine of GR grade from Merck and Millipore water of resistivity 18.2 M Ω cm were used for all studies. No further purification was done. The solubility was determined gravimetrically for pure ADP and ADP doped with small amount (5 mol%) of LAHCl and L-alanine separately as additives. Polythermal method (Nyvlt et al 1970) was adopted for the metastable zonewidth studies of pure and doped ADP solutions. The ADP solution (600 ml) saturated at 30 °C was prepared according to the solubility diagram with continuous stirring using a magnetic stirrer and the solutions were filtered. Three similar beakers with 200 ml solution each were used; the first beaker contained pure ADP solution whereas the second and the third beakers contained 5 mol% LAHCl and 5 mol% L-alanine doped ADP solutions respectively. Then pure and doped ADP solutions were kept in a Constant Temperature Bath (CTB) with cooling facility. After stirring for 6 h, the solution was slowly cooled at a desired cooling rate

of 4 °C/h, until the first crystal appeared. The experiments were repeated for different saturation temperatures (30–50) °C with the interval of 5 °C and the corresponding metastable zonewidths were measured. Several nucleation runs (7–9 times) were carried out under controlled conditions and reproducible results with the accuracy of $\pm 0.25\%$ were obtained. The metastability limit of LAHCl added solution and L-alanine added solution is shown in Figure 2 in comparison with the pure system.

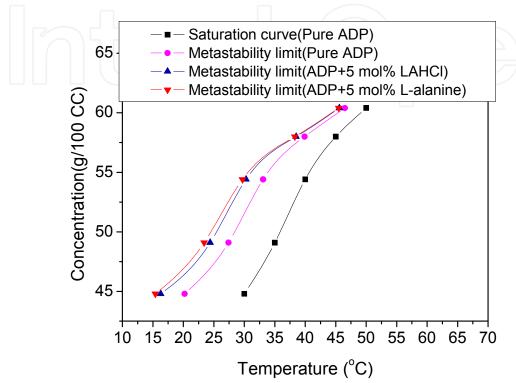


Fig. 2. Saturation and metastability limit curves of pure, LAHCl and L-alanine added ADP solutions.

It is obvious from the figure that the zone widths for all the solutions decrease as the temperature increases. At the same time, the addition of dopants enhances the metastable zonewidth of ADP solutions for all the temperatures studied in this work, and makes the ADP solution more stable. During the experiment, the number of tiny crystals formed by spontaneous nucleation was appreciably reduced in the case of the doped solutions compared with the pure one. Among the two additives, the additive L-alanine enhances the metastable zonewidth of ADP than the other additive LAHCl especially at lower temperatures. The addition of these amino acid additives can make ADP solution more stable.

2.2 Determination of induction period

The induction period, a measure of the nucleation rate was determined experimentally for ADP solutions with and without the presence of additives at different supersaturations by means of isothermal method (Zaitseva et al., 1995). The "direct vision method" by naked eye is used for measuring induction period. Aqueous solutions of various supersaturated concentrations were prepared. Supersaturation was obtained by natural cooling. Supersaturated solutions of equal volume (100 ml) were taken in the cells at a higher

temperature. As the temperature of the cell reached the experimental temperature (35 °C), the time was noted. Once the nucleation occurred, it grew quickly and a bright sparkling particle was seen. The time of observation of the sparkling particle in the cell from the time at which the solution reaches the experimental temperature of nucleation (temperature of beginning of nucleation) gives the induction period of nucleation. The effect of heterogeneous nucleation due to scratching on the inner wall of the nucleation cell was reduced by choosing a glass beaker without scratches. Experiments were performed at selected degrees of supersaturation (c/c_o), viz., 1.25, 1.275, 1.3, c_o being the mole fraction of solute in supersaturated solution and c_o is the equilibrium concentration. Several nucleation runs (5–7 times) were carried out under controlled conditions and reproducible results with the accuracy of $\pm 0.25\%$ were obtained. The experimental results of induction period for pure and doped ADP solutions are presented in Figure 3.

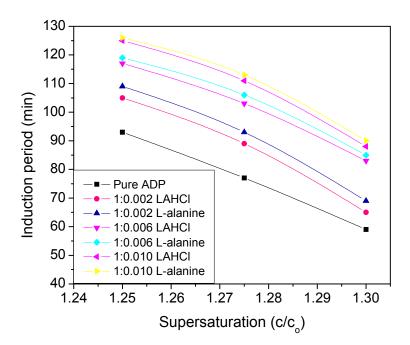


Fig. 3. Values of induction period against supersaturation.

Considering the principles of homogeneous and heterogeneous nucleation theories, the free energy of formation of a nucleus under heterogeneous nucleation is less than that of a homogeneous condition (Sangwal 1996; Srinivasan et al 1999). Considering the additive added system it can be noticed that the induction period of doped ADP is higher than that of pure and it increases with the increase in the additive concentration. Among the additives, L-alanine has a longer higher induction period than LAHCl at every concentration. The presence of additives in the system affects the nucleation behavior very considerably. This may be due to the suppression of chemical activity of the metal ions present in the ADP solution (Mullin 1993).

2.3 Growth rate measurements

The growth rate of a crystal is known to be changed by traces of certain impurities or additives. In this work, the influence of the additives on the growth rate of ADP crystals is

determined by the weighing method put forwarded by Kubota et al (1995). By this method, the growth rate of a crystal is defined as

$$G_g = (m - m_o)/m_o \Delta \theta \tag{1}$$

where m_o is the initial mass of the crystal (kg), m is the final mass of the crystal (kg), and $\Delta\theta$ is the growth time. Here growth time is taken as 1 h. A single crystal with a size of 5–10 mm was used as the seed for the experiment. The seed crystal (of mass m_o) was suspended in the solution in 500 ml glass vessel (working volume: 400 ml) for 1 h ($\Delta\theta$) for growth. The solution was continuously stirred throughout the process. Supercooling was varied from 2 to 10 °C by changing the growth temperature. The same procedure is done for pure and doped ADP crystals. Figure 4 shows the growth rates of pure and doped ADP crystals.

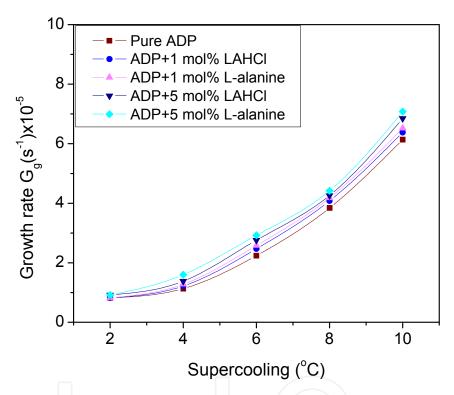


Fig. 4. Variation of mass growth rates for pure and doped ADP crystals.

The presence of additives is found to have an influence on the growth rate. The role of additives during the growth process could be visualized as follows. The additives LAHCl and L-alanine have higher solubility than that of the crystallizing substance (ADP). The additives might have changed the thermodynamic parameters, i.e. the surface concentration of the growth species and the surface energy. An increase in solubility by the addition of LAHCl and L-alanine may lead to decrease in the surface energy, which consequently decreases the rates of layer displacement that cause an increase in the growth rate (Sangwal 1996).

2.4 Crystal growth

In the present work, ADP crystals doped with 5 mol% LAHCl and L-alanine separately were grown from aqueous solution with a simple apparatus that can be applied in certain

forced convection configurations to maintain a higher homogeneity of the solution. This apparatus consists of seed rotation controller coupled with a stepper motor, which is controlled by using a microcontroller based drive. This controller rotates the seed holder in the crystallizer. The seed crystal is mounted on the center of the platform made up of acrylic material and is fixed into the crystallizer. The seed mount platform stirs the solution very well and makes the solution more stable, which results in better crystal quality. The schematic diagram of the seed rotation controller designed for low temperature solution growth method is shown in Figure 5. The uniform rotation of the seed is required to avoid stagnant regions or re-circulating flows, otherwise inclusions in the crystals will be formed due to inhomogeneous supersaturation in the solution (Fu et al., 2000).

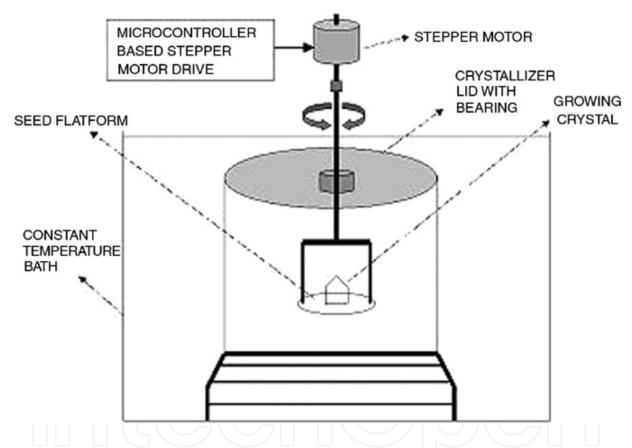


Fig. 5. Schematic diagram of the seed rotation controller.

The crystal growth was carried out in a 5000 ml standard crystallizer used for conventional crystal growth by using the method of temperature reduction. The temperature of solution in the crystallizer was controlled using a CTB and the temperature fluctuations are less than 0.01 °C. The saturation temperature was 50 °C. The solution was filtered by filtration pump and Whatman filter paper of pore size 11 μ m under slight pressure in a closed system to remove extraneous solid and colloidal particles, which may act as the centers of spontaneous nucleation during growth. Then the solutions were overheated at 70 °C for 24 h. This duration of overheating was found to be effective to destroy the molecule clusters existing in the solution and to make the solution stable against spontaneous nucleation

under a high supersaturation (Zaitseva et al., 1995; Nakatsuka et al., 1997). Then the temperature of the solution was reduced to 3–5 °C higher than saturation point (50 °C) at 1 °C/h. After that temperature was reduced to the saturation point at 1 °C/day and the seed crystal was mounted on the platform. The rotation rate of the platform was 40 rpm. From the saturation point, the temperature was decreased at 0.1 °C/day at the beginning of the growth. As the growth progressed, the temperature lowering rate was increased up to 1 °C/day. After the growth period of 30 days, crystals were harvested. The as–grown crystals are shown in Figure 6. In the figure, (a) is ADP doped with L-Alanine and (b) is ADP doped with LAHCI.

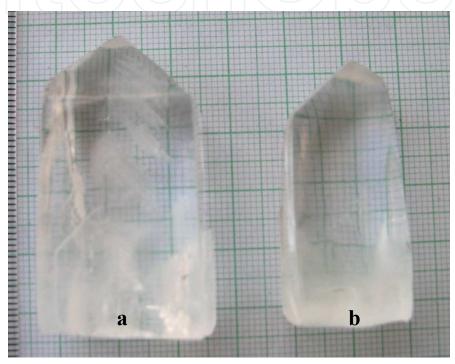


Fig. 6. Photograph of L-alanine doped ADP crystal and LAHCl doped ADP crystal

For various characterization techniques, pure and doped (in concentrations 1 and 5 mol %) ADP crystals were grown by slow cooling method under identical conditions.

3. Analysis of physicochemical studies

3.1 Powder XRD studies

The powder X-ray diffraction is useful for confirming the identity of a solid material and determining crystallinity and phase purity. Grown crystals were ground using an agate mortar and pestle in order to determine the crystal phases by X-ray diffraction. Powder X-ray diffraction study was carried out by employing SEIFERT, 2002 (DLX model) diffractometer with CuK_{α} (λ = 1.5405 Å) radiation using a tube voltage and current of 40 kV and 30 mA respectively. Figure 7 shows X-ray powder diffraction patterns of ADP doped with LAHCl (5 mol%) and ADP doped with L-alanine (5 mol%) compared with that of pure ADP crystal. X-ray powder diffraction patterns of pure ADP and doped ADP crystals are identical. As seen in the figure, no additional peaks are present in the XRD spectra of doped ADP crystals, showing the absence of any additional phases due to doping.

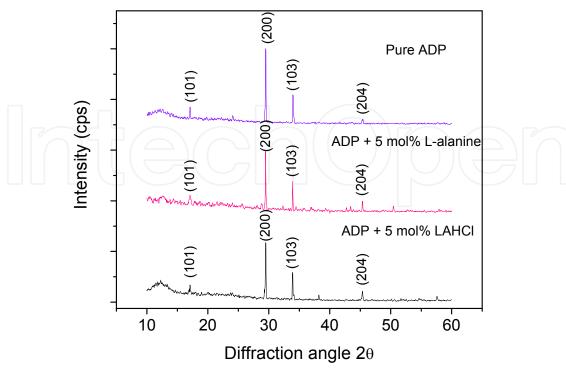


Fig. 7. X-ray powder diffraction patterns of ADP crystals.

3.2 High-resolution x-ray diffraction (HRXRD) analysis

The crystalline perfection of the grown single crystals was characterized by HRXRD analysis by employing a multicrystal X-ray diffractometer designed and developed at National Physical Laboratory (Lal et al., 1989). Figure 8 shows the schematic diagram of the multicrystal X-ray diffractometer. The divergence of the X-ray beam emerging from a fine focus X-ray tube (Philips X-ray Generator; 0.4 mm × 8 mm; 2kWMo) is first reduced by a long collimator fitted with a pair of fine slit assemblies. This collimated beam is diffracted twice by two Bonse-Hart (Bonse et al., 1965) type of monochromator crystals and the thus diffracted beam contains well resolved MoK α_1 and MoK α_2 components. The MoK α_1 beam is isolated with the help of fine slit arrangement and allowed to further diffract from a third (111) Si monochromator crystal set in dispersive geometry (+, -, -). Due to dispersive configuration, though the lattice constant of the monochromator crystal and the specimen are different, the dispersion broadening in the diffraction curve of the specimen does not arise. Such an arrangement disperses the divergent part of the MoKα₁ beam away from the Bragg diffraction peak and thereby gives a good collimated and monochromatic MoKα₁ beam at the Bragg diffraction angle, which is used as incident or exploring beam for the specimen crystal. The dispersion phenomenon is well described by comparing the diffraction curves recorded in dispersive (+, -, -) and non-dispersive (+, -, +) configurations (Bhagavannarayana 1994). This arrangement improves the spectral purity ($\Delta\lambda/\lambda \ll 10^{-5}$) of the $MoK\alpha_1$ beam. The divergence of the exploring beam in the horizontal plane (plane of diffraction) was estimated to be << 3 arc s. The specimen occupies the fourth crystal stage in symmetrical Bragg geometry for diffraction in (+, -, -, +) configuration. The specimen can be rotated about a vertical axis, which is perpendicular to the plane of diffraction, with minimum angular interval of 0.4 arc s. The diffracted intensity is measured by using an inhouse developed scintillation counter. To provide two-theta $(2\theta_B)$ angular rotation to the detector (scintillation counter) corresponding to the Bragg diffraction angle (θ_B) , it is coupled to the radial arm of the goniometer of the specimen stage. The rocking or diffraction curves were recorded by changing the glancing angle (angle between the incident X-ray beam and the surface of the specimen) around the Bragg diffraction peak position θ_B (taken as zero for the sake of convenience) starting from a suitable arbitrary glancing angle. The detector was kept at the same angular position $2\theta_B$ with wide opening for its slit, the so-called ω scan.

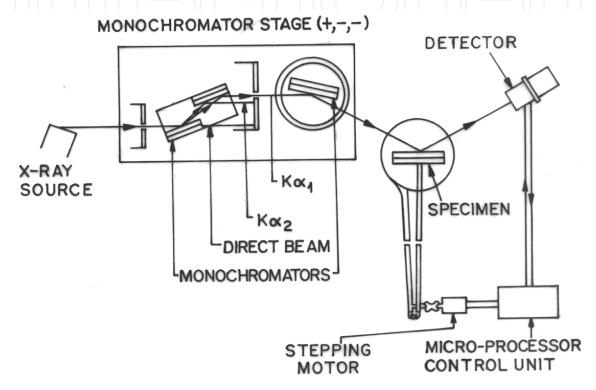


Fig. 8. Schematic line diagram of multicrystal X-ray diffractometer designed, developed and fabricated at National Physical Laboratory

Before recording the diffraction curve to remove the non-crystallized solute atoms remained on the surface of the crystal and also to ensure the surface planarity, the specimen was first lapped and chemically etched in a non preferential etchant of water and acetone mixture in 1:2 ratio

Figure 9 shows the high-resolution diffraction curve (DC) recorded for LAHCl doped (5 mol%) ADP specimen and Figure 10 shows the DC recorded for L-alanine doped (5 mol%) ADP specimen using (200) diffracting planes in symmetrical Bragg geometry by employing the multicrystal X-ray diffractometer with MoK α_1 radiation. The curves are very sharp having full width at half maximum (FWHM) of 8 arc s for LAHCl doped ADP and 5 arc s for L-alanine doped ADP crystals as expected for nearly perfect crystals from the plane wave dynamical theory of X-ray diffraction (Batterman et al., 1964). The absence of additional peaks and the very sharp DC shows that the crystalline perfection of the specimen crystals is extremely good without having any internal structural grain boundaries and mosaic nature. The high reflectivity ($\approx 50\%$ in LAHCl doped and $\approx 60\%$ in L-alanine doped) and the very small value of FWHM indicate that even the unavoidable point defects like self interstitials

and vacancy defects (Lal et al., 1989) are also extremely low. However, the quality of L-alanine doped ADP specimen is better than that of LAHCl doped specimen.

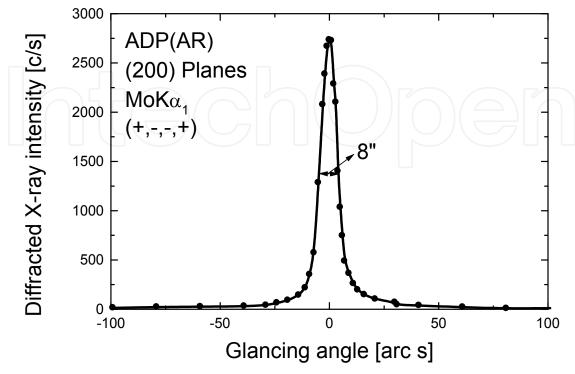


Fig. 9. Diffraction curve recorded for LAHCl doped ADP single crystal using (200) diffracting planes.

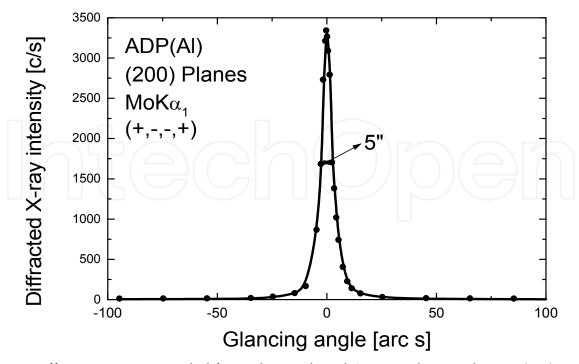


Fig. 10. Diffraction curve recorded for L-alanine doped ADP single crystal using (200) diffracting planes.

3.3 FTIR spectral analysis

The influence of additives used in this work on the vibration frequencies of functional groups of pure ADP crystal has been identified by FTIR spectroscopy. The FTIR spectra were recorded in the region 400-4000 cm⁻¹ using a Perkin-Elmer FTIR Spectrum RXI spectrometer by KBr pellet technique. Figure 11 shows the FTIR spectra of the pure ADP, ADP doped with LAHCl (1 mol%) and ADP doped with L-alanine (1 mol%). The broad band in the high energy region is due to O-H vibrations of water, P-O-H group and N-H vibrations of ammonium (Rajesh et al., 2009). The broadness is due to the hydrogen bonding interaction with adjacent molecules (Rani et al., 2011). The peak at 2370 cm⁻¹ is due to the combination band of vibrations occurring at 1293 and 1290 cm⁻¹. The bending vibrations of water give the peak at 1646 cm⁻¹. The peak at 1402 cm⁻¹ is due to bending vibrations of ammonium (Rani et al., 2011). The P-O-H vibrations give the peaks at 1090 and 930 cm⁻¹. The PO₄ vibrations give their peaks at 544 and 470 cm⁻¹.

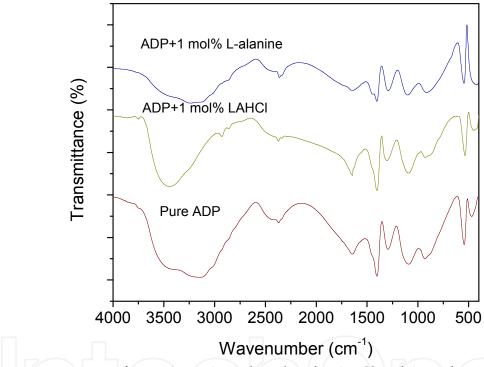


Fig. 11. FTIR spectra of pure ADP, ADP doped with LAHCl and ADP doped with L-alanine.

In the spectrum of ADP doped with LAHCl, the intense band appearing at 3442 cm⁻¹ includes O-H vibrations and N-H vibrations of ammonium and amino acid. Although this spectrum carries similar features as that of ADP, there is a distinct evidence for the presence of LAHCl in the lattice of ADP. The peaks appearing at 2928 cm⁻¹ and about 2890 cm⁻¹ are due to CH₂ vibrations of LAHCl. In addition, shift in the peak positions of P-O-H and PO₄ vibrations compared to ADP established the presence of the additive in the lattice of ADP. In the spectrum of ADP with L-alanine also, there is a significant shift in the peak positions. For example, the PO₄ vibration of the parent is shifted from 470 to 419 cm⁻¹. Similarly the P-O-H vibrations at 1090 and 930 cm⁻¹ of the parent are shifted to 1101 and 913 cm⁻¹. Such a shift establishes the presence of L-alanine in the lattice of ADP. As the vibrations of L-alanine are not clearly resolved from the spectrum of the parent, it might be in a trace amount below the deductibility limit. There is a slight evidence of CH₂

vibrations of L-alanine just below 3000 cm⁻¹. All these support the presence of L-alanine in the lattice of ADP.

3.4 Dielectric studies

The dielectric constant is one of the basic electrical properties of solids. Dielectric properties are correlated with the electro-optic property of the crystals (Aithal et al., 1997). The capacitance (C_{crys}) and dielectric loss ($\tan \delta$) of pure and doped ADP crystals were measured using the conventional parallel plate capacitor method for temperatures from 313 to 423 K with frequency (f) of 1 kHz. Good quality transparent crystals of size $7 \times 7 \times 2$ mm³ were used for the measurements. The dimensions of the samples were determined using a traveling microscope (LC = 0.001 cm). Samples were coated with good quality graphite in order to obtain a good ohmic contact. The measurements were done on a-b directions of the crystals. The samples were annealed up to 423 K to remove water molecules if present. The observations were made while cooling the sample and the air capacitance (C_{air}) was also measured. Several trials of experiments were conducted.

The dielectric constant of the crystal was calculated using the relation

$$\varepsilon_r = \frac{C_{crys}}{C_{air}} \tag{2}$$

As the crystal area was smaller than the plate area of the cell, parallel capacitance of the portion of the cell not filled with the crystal was taken into account and, consequently, the above equation becomes

$$\varepsilon_{r} = \left(\frac{C_{crys} - C_{air} \left(1 - \frac{A_{crys}}{A_{air}}\right)}{C_{air}}\right) \left(\frac{A_{air}}{A_{crys}}\right)$$
(3)

where A_{crys} is the area of the crystal touching the electrode and A_{air} is the area of the electrode.

Figure 12 shows the temperature dependence of dielectric constants of pure and LAHCl doped (1 and 5 mol%) ADP crystals. Temperature dependence of dielectric constants of pure and L-alanine doped (1 and 5 mol%) ADP crystals are depicted in Figure 13.

It is observed from the figures that the dielectric constant increases with increase in temperature. This is normal dielectric behaviour of an antiferroelectric ADP crystal. In the present study, it has been observed that the LAHCl and L-alanine doped ADP crystals have lower ϵ_r values compared to pure. Among these, 5 mol% doped crystals have lower ϵ_r values than 1 mol% doped ones. Suitable dopants added in suitable concentrations can reduce the ϵ_r value to a lower one as observed in the case of KDP single crystals added with urea (Goma et al., 2006). Thus, in effect, the present study indicates that LAHCl and L-alanine doped ADP crystals are not only potential NLO materials but also low ϵ_r value dielectric materials, which will be useful for microelectronic industries and electro-optic modulators. The dielectric loss of the grown crystals for various temperatures at the frequency (1 kHz) is shown in Figures 14 and 15. It is observed that the dielectric loss increases with increase in temperature for the crystals. It reveals that doped crystals have lower dielectric loss values compared to pure crystals.

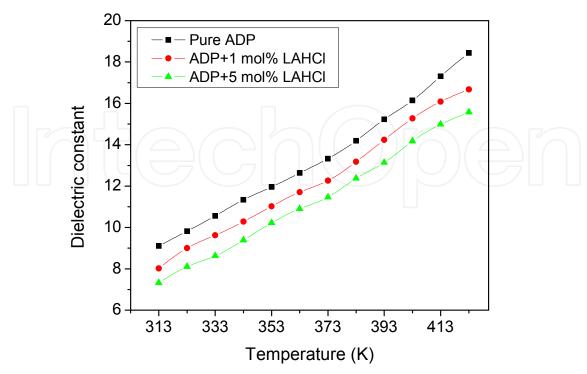


Fig. 12. Variation of dielectric constant with temperature for pure and LAHCl doped ADP crystals.

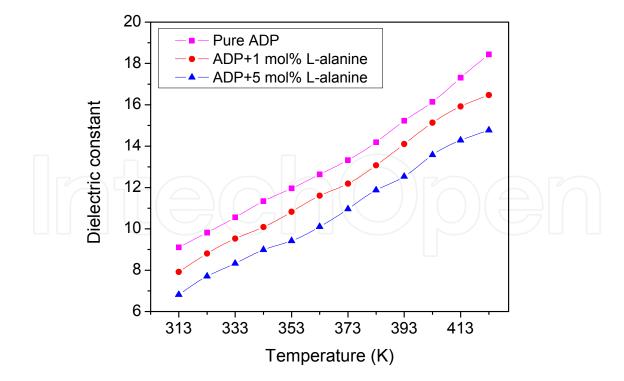


Fig. 13. Variation of dielectric constant with temperature for pure and L-alanine doped ADP crystals.

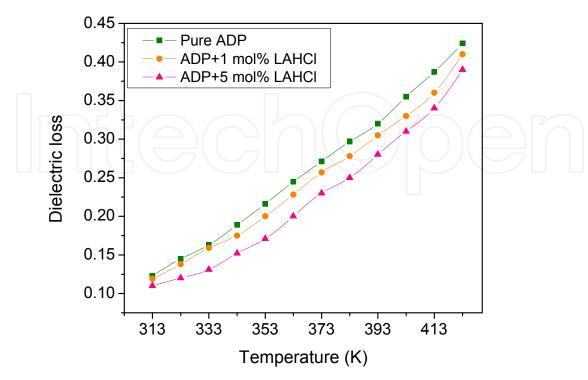


Fig. 14. Variation of dielectric loss with temperature for pure and LAHCl doped ADP crystals.

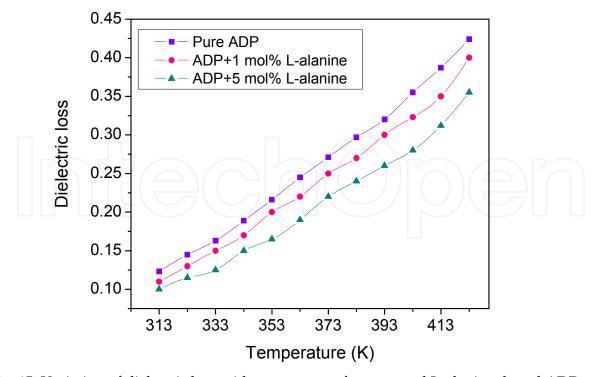


Fig. 15. Variation of dielectric loss with temperature for pure and L-alanine doped ADP crystals.

3.5 Optical transmission studies

Optical transmission spectra were recorded for the samples obtained from pure as well as from doped crystals grown by the slow cooling method. The spectra were recorded in the wavelength region 200–1100 nm using Lambda 35 spectrophotometer. Crystal plates with 2 mm thickness were used for the study. The reported value of the optical transparency for ADP is from 184 to 1500 nm (Dmitriev et al., 1991). The UV-vis-NIR spectra recorded for pure and doped ADP crystals are shown in Figure 16. It is clear from the figure that the crystals have sufficient transmission (pure ADP has 70% whereas LAHCl and L-alanine doped ADP have 78% and 82% respectively) in the entire visible and IR region. The optical transparency of the ADP crystal is increased by the addition of LAHCl and L-alanine. The addition of the amino acid dopants in the optimum conditions to the solution is found to suppress the inclusions and improve the quality of the crystal with higher transparency.

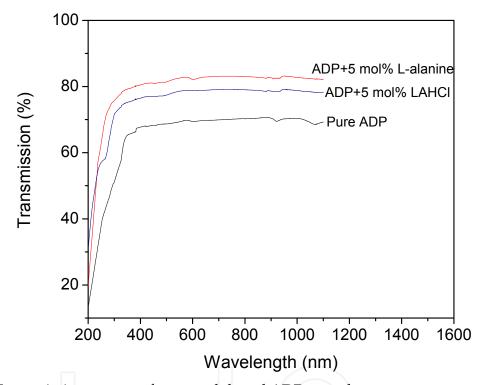


Fig. 16. Transmission spectra of pure and doped ADP crystals.

3.6 NLO property

Kurtz and Perry (1968) proposed a powder second harmonic generation method for comprehensive analysis of the second order nonlinearity. This is an important method for characterizing the materials before going through the long and tedious process of growing large optical quality crystals. To determine the SHG conversion efficiency of doped crystals, pure and doped crystals were ground into powder and densely filled into the cells. A Q-switched Nd: YAG laser (DCR11) was used as a light source. A laser beam of fundamental wavelength 1064 nm, 8 ns pulse width, with 10 Hz pulse rate was made to fall normally on the sample cell. The power of the incident beam was measured using a power meter. The transmitted fundamental wave was passed over a monochromator (Czemy Turner monochromator), which separates 532 nm (second harmonic signal) from 1064 nm, and absorbed by a CuSO₄ solution, which removes the 1064 nm light, and passed through BG34

filter to remove the residual 1064 nm light and an interference filter with bandwidth of 4 nm and central wavelength of 532 nm. The green light was collected by a photomultiplier tube (Hamamatsu). The input laser energy incident on the powdered sample was 1.35 mJ/pulse. An emission of green light was seen in all the samples. It was observed that the measured SHG efficiency of L-alanine doped (5 mol%) ADP was 1.75 and LAHCl doped (5 mol%) ADP was 1.5 that of pure ADP.

3.7 Piezoelectric measurements

Piezoelectricity is the ability of certain crystals to generate an electric charge when subjected to mechanical stress. The piezoelectric property is related to the polarity of the material (Ge et al 2008). The piezoelectric studies were made using piezometer system. A precision force generator applied a calibrated force (0.25 N) which generated a charge on the piezoelectric material under test. An oscilloscope gives the output in d₃₃ coefficient in of pC/N units. Piezoelectric measurements were conducted for the grown crystals by without polishing of the crystal. Pure ADP crystal gives the piezoelectric coefficient (d₃₃) value of 0.37 pC/N. The obtained piezoelectric coefficient (d₃₃) values for LAHCl doped (5 mol%) ADP and L-alanine doped (5 mol%) ADP crystals are 0.68 and 0.8 pC/N. Thus, d₃₃ value of 5 mol% LAHCl doped ADP crystal is 1.84, while and for 5 mol% L-alanine doped ADP crystal it is 2.16 times higher than that of pure ADP crystal. Greater crystalline perfection may be the reason for the increase in piezoelectric efficiency.

4. Conclusions

With the aim of improving the quality of ADP crystals with better optical properties for both academic and industrial uses, an attempt has been made in this present work to grow the ADP crystals by doping it with new additives L-arginine monohydrochloride and L-alanine. The addition of these amino acid materials enhances the metastable zone width and induction period of pure ADP solution. Also, during the experiment it was observed that the number of tiny crystals formed by spontaneous nucleation was appreciably reduced in the case of doped solution. It is believed that the addition of these amino acid materials suppresses the activities of the metal ion impurities present in the solution which enables larger metastable zone width and faster growth rate. HRXRD curves recorded for 5 mol% doped crystals have excellent crystalline perfection. The FTIR spectrum shows that amino acid additives have entered into the ADP crystals. The transmission spectrum reveals that the crystal has sufficient transmission in the entire visible and IR region. The SHG conversion efficiency and piezoelectric coefficient values of doped crystals are higher than that of pure. This study will help the growth of high quality large size ADP single crystals.

5. References

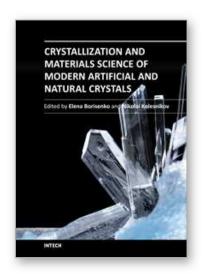
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